



## SOT-363 Plastic-Encapsulate Transistors

### BC846PN DUAL TRANSISTOR (NPN+PNP)

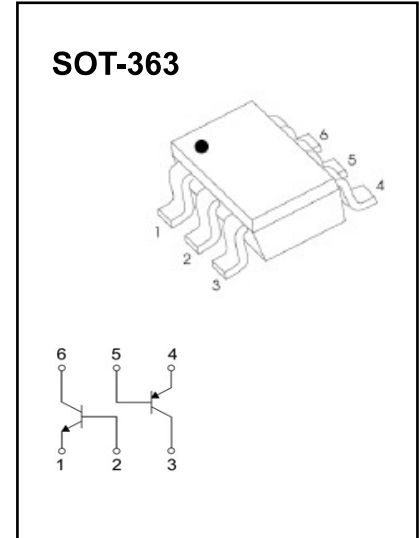
#### FEATURES

- Epitaxial Die Construction
- Two isolated NPN/PNP(BC846W+BC856W) Transistors in one package

#### MARKING: BB

#### MAXIMUM RATINGS TR1 (T<sub>a</sub>=25°C unless otherwise noted)

Symbol	Parameter	Value	Units
V <sub>CB0</sub>	Collector-Base Voltage	80	V
V <sub>CEO</sub>	Collector-Emitter Voltage	65	V
V <sub>EBO</sub>	Emitter-Base Voltage	6	V
I <sub>C</sub>	Collector Current –Continuous	0.1	A
P <sub>C</sub>	Collector Power Dissipation	200	mW
T <sub>J</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55-150	°C



#### CHARACTERISTICS of TR1 (NPN Transistor) (T<sub>a</sub>=25°C unless otherwise specified)

Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> =10μA, I <sub>E</sub> =0	80			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0	65			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =1μA, I <sub>C</sub> =0	6			V
Collector cut-off current	I <sub>CB0</sub>	V <sub>CB</sub> =30V, I <sub>E</sub> =0			15	nA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			15	nA
DC current gain	h <sub>FE</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	200		450	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA			0.25	V
	V <sub>CE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA			0.6	V
Base-emitter saturation voltage	V <sub>BE(sat)</sub>	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA		0.7		V
	V <sub>BE(sat)</sub>	I <sub>C</sub> =100mA, I <sub>B</sub> =5mA		0.9		V
Base-emitter voltage	V <sub>BE(on)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	0.58		0.7	V
	V <sub>BE(on)</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA			0.72	V
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			6.0	pF
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=100MHz	100			MHz
Noise figure	NF	V <sub>CE</sub> =5V, I <sub>C</sub> =0.2mA, f=1kHz, R <sub>g</sub> =2KΩ, Δf=200Hz			10	dB

# SOT-363 Plastic-Encapsulate Transistors

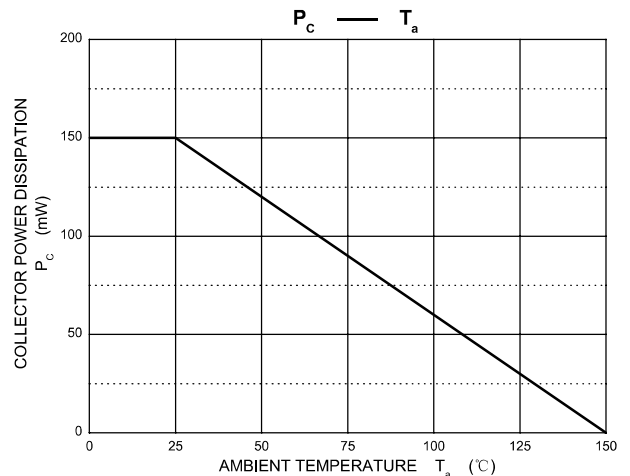
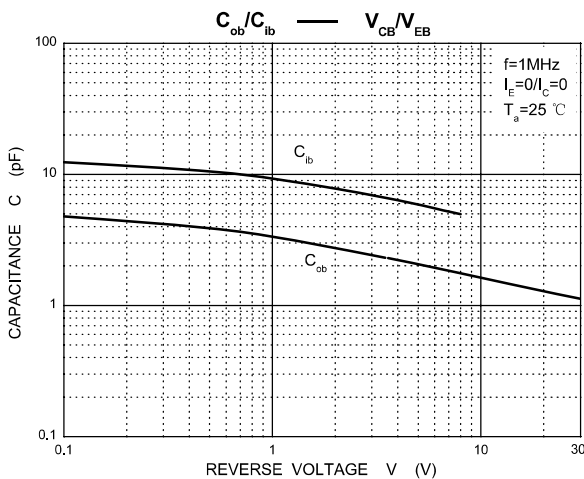
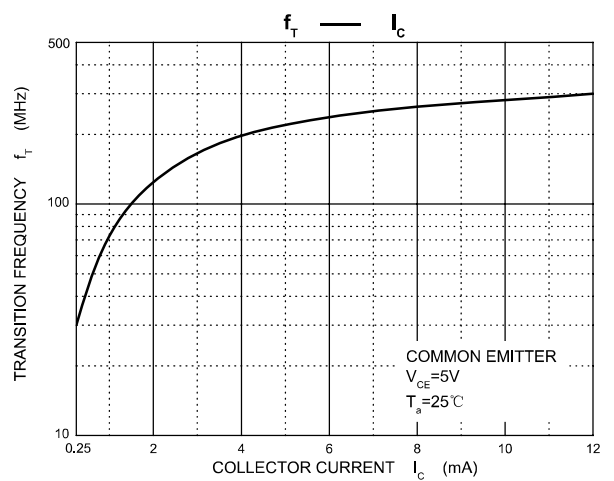
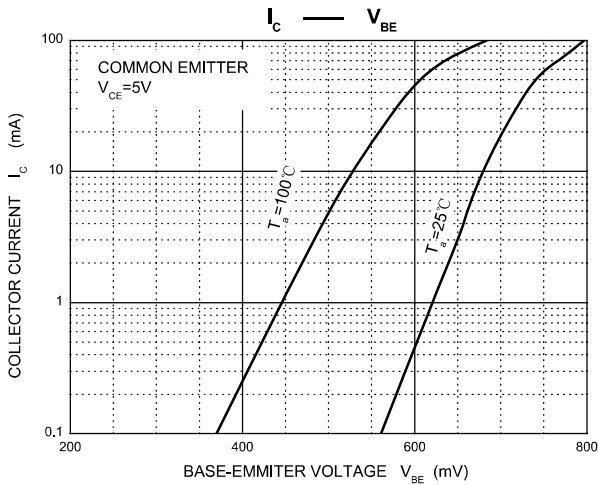
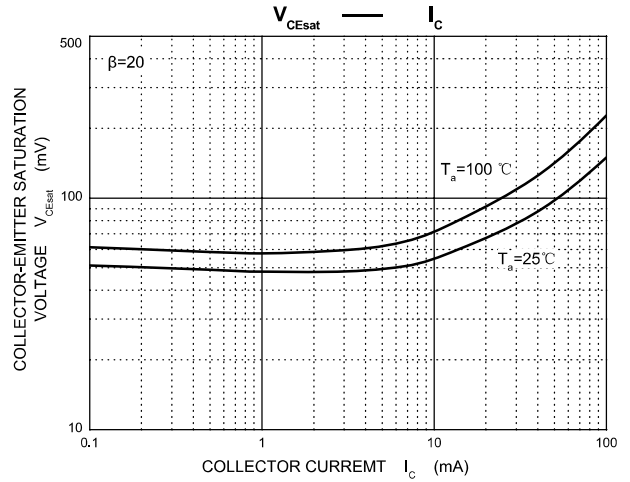
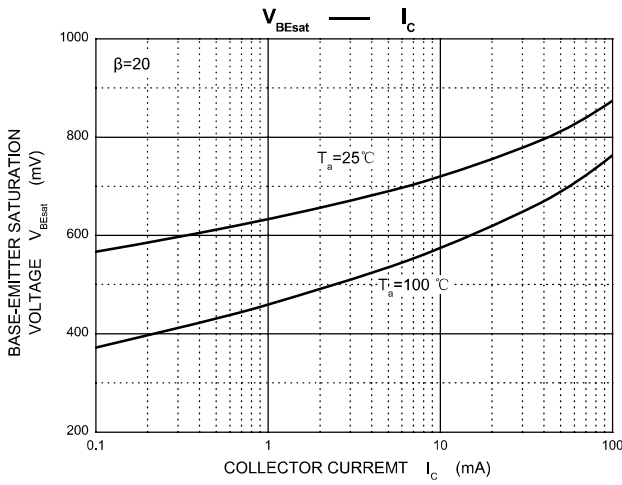
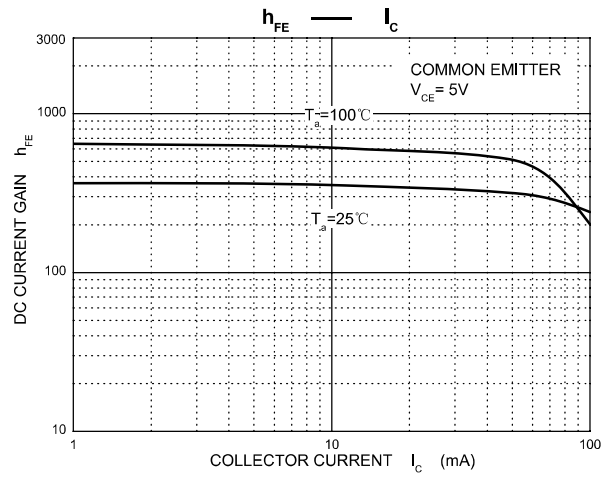
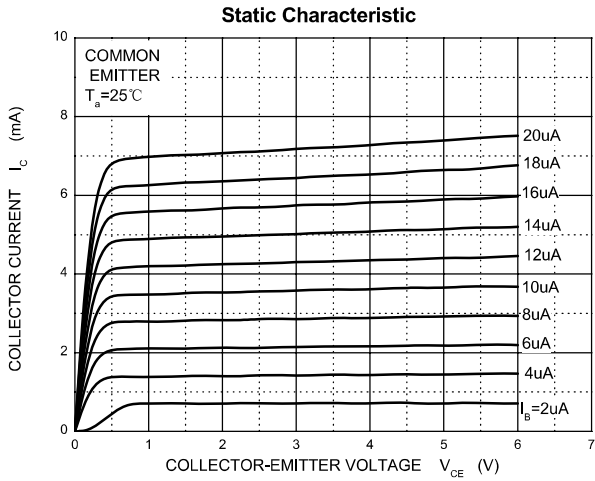
## **BC846PN** DUAL TRANSISTOR (NPN+PNP)

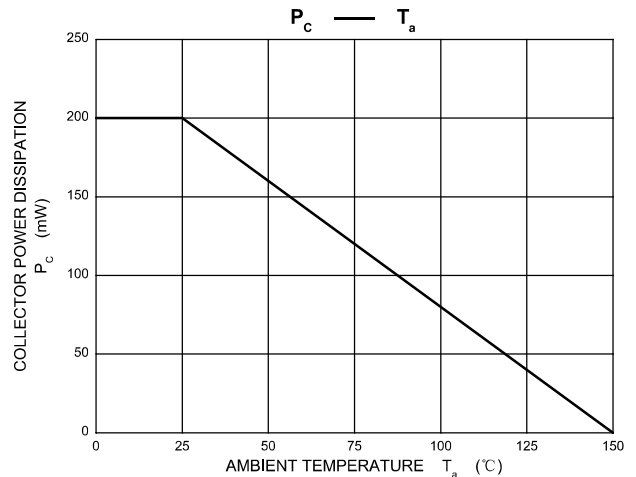
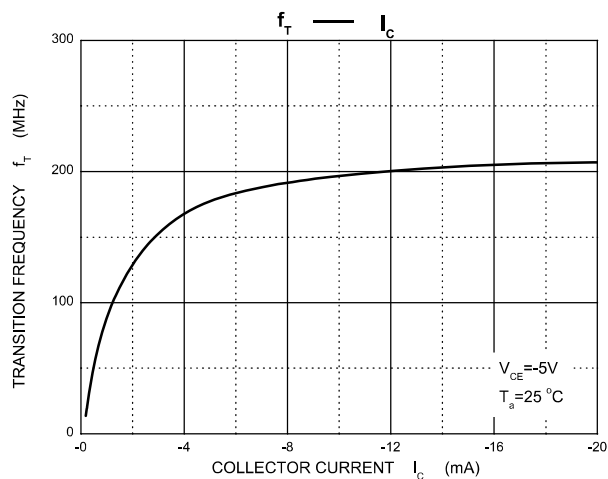
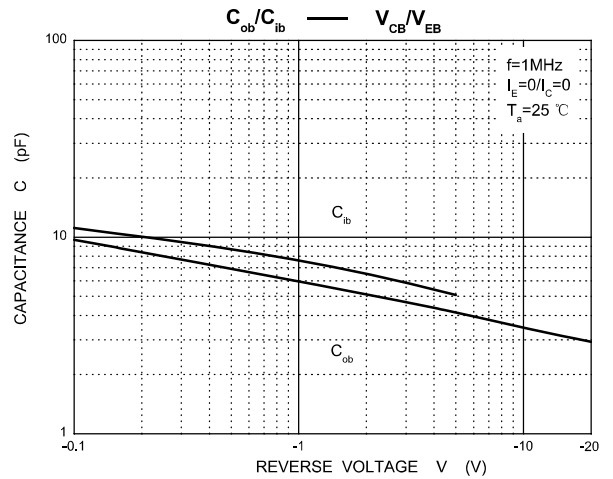
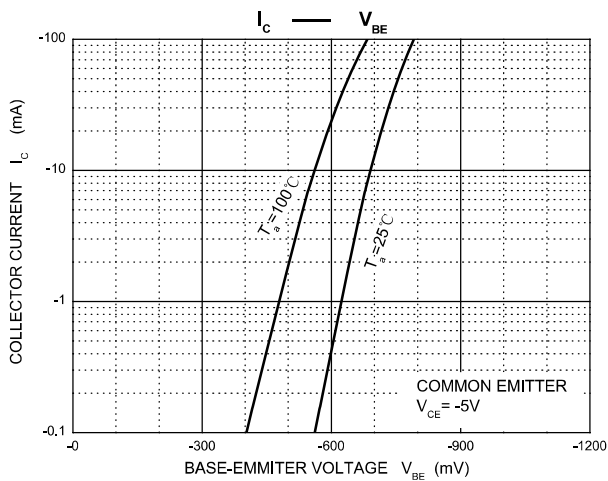
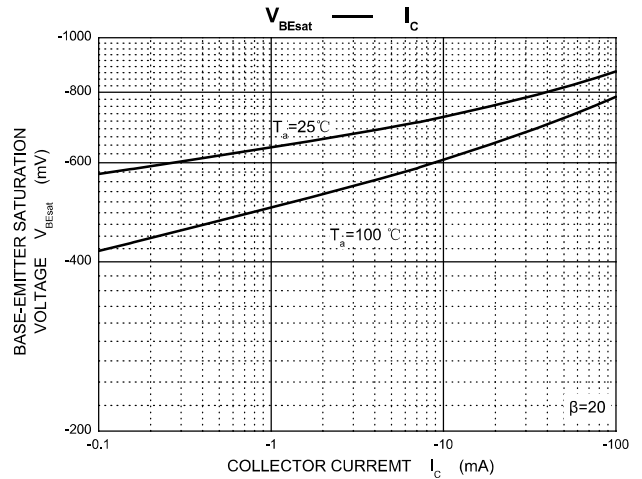
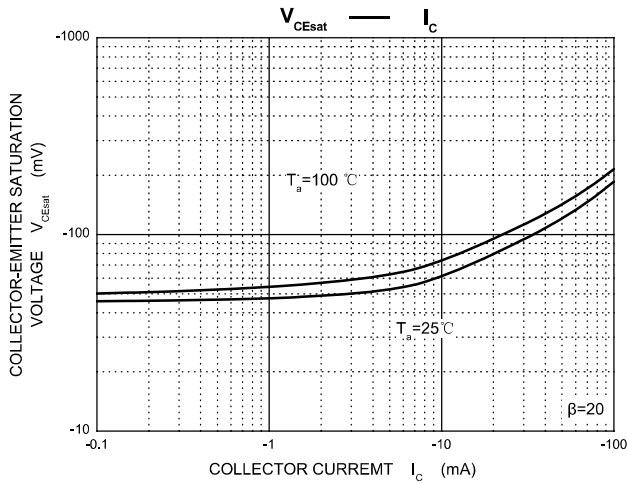
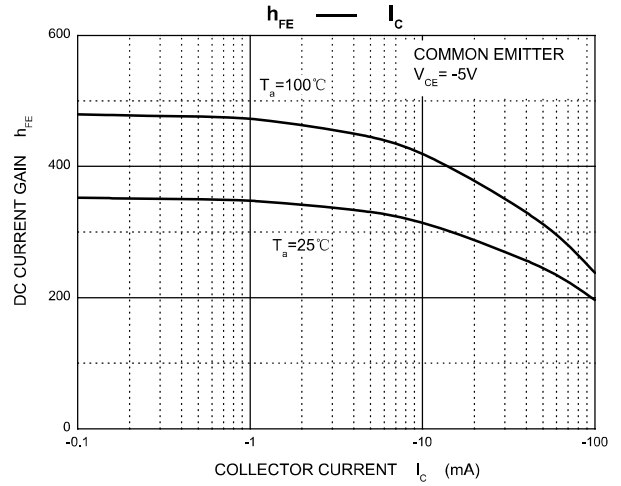
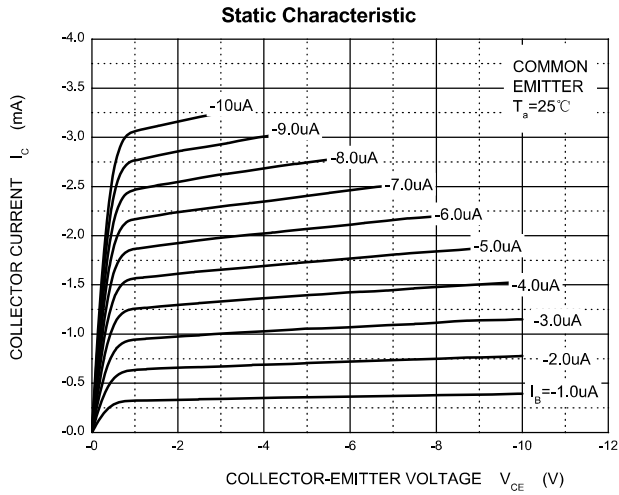
### MAXIMUM RATINGS TR2 ( $T_a=25^{\circ}\text{C}$ unless otherwise noted)

Symbol	Parameter	Value	Units
$V_{CBO}$	Collector-Base Voltage	-80	V
$V_{CEO}$	Collector-Emitter Voltage	-65	V
$V_{EBO}$	Emitter-Base Voltage	-5	V
$I_C$	Collector Current –Continuous	-0.1	A
$P_{C^*}$	Collector Power Dissipation	200	mW
$T_J$	Junction Temperature	150	$^{\circ}\text{C}$
$T_{stg}$	Storage Temperature	-55-150	$^{\circ}\text{C}$

### CHARACTERISTICS of TR2 (PNP Transistor) ( $T_a=25^{\circ}\text{C}$ unless otherwise specified)

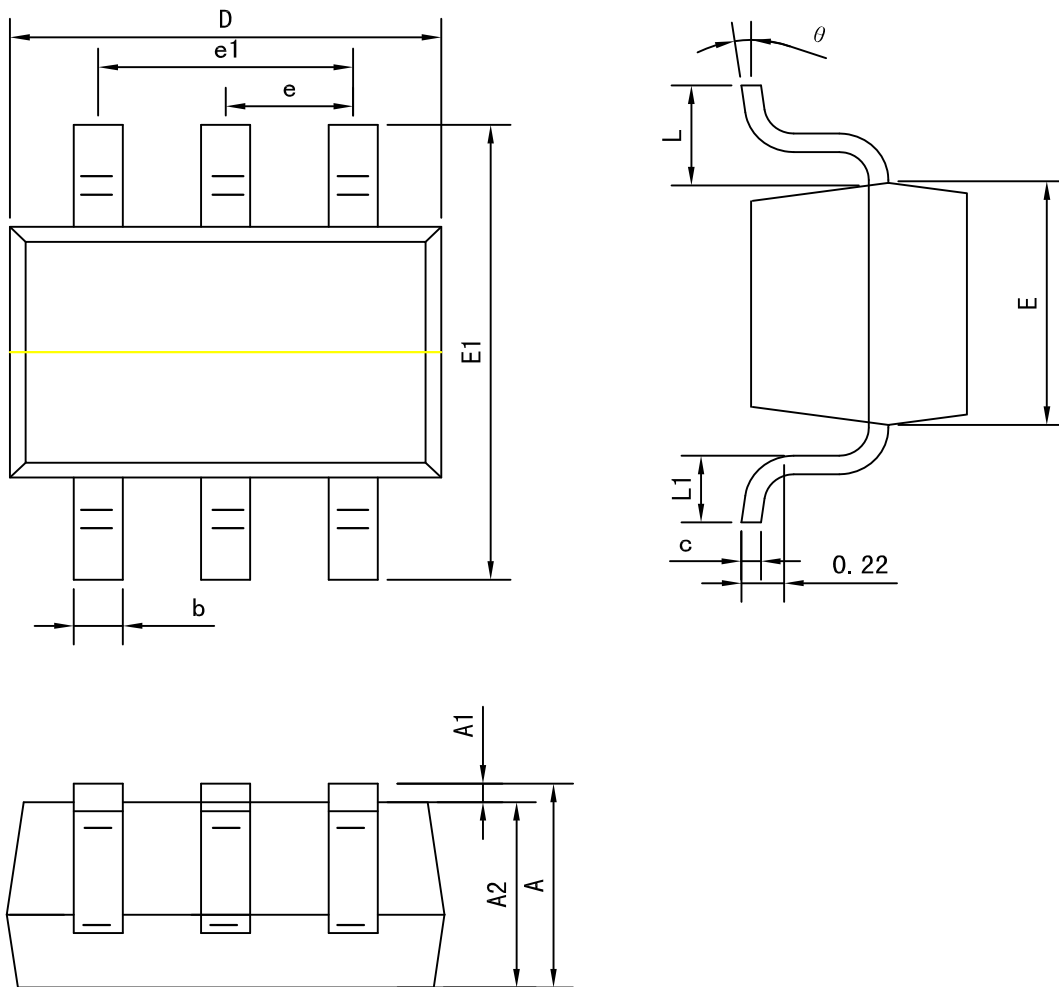
Parameter	Symbol	Test conditions	MIN	TYP	MAX	UNIT
Collector-base breakdown voltage	$V_{(BR)CBO}$	$I_C=-10\mu\text{A}, I_E=0$	-80			V
Collector-emitter breakdown voltage	$V_{(BR)CEO}$	$I_C=-10\text{mA}, I_B=0$	-65			V
Emitter-base breakdown voltage	$V_{(BR)EBO}$	$I_E=-1\mu\text{A}, I_C=0$	-5			V
Collector cut-off current	$I_{CBO}$	$V_{CB}=-30\text{V}, I_E=0$			-15	nA
Emitter cut-off current	$I_{EBO}$	$V_{EB}=-5\text{V}, I_C=0$			-15	nA
DC current gain	$h_{FE1}$	$V_{CE}=-5\text{V}, I_C=-2\text{mA}$	220		475	
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C=-10\text{mA}, I_B=-0.5\text{mA}$			-0.3	V
	$V_{CE(sat)}$	$I_C=-100\text{mA}, I_B=-5\text{mA}$			-0.65	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C=-10\text{mA}, I_B=-0.5\text{mA}$		-0.7		V
	$V_{BE(sat)}$	$I_C=-100\text{mA}, I_B=-5\text{mA}$			-0.95	V
Base-emitter voltage	$V_{BE(on)}$	$V_{CE}=-5\text{V}, I_C=-2\text{mA}$	-0.6		-0.75	V
	$V_{BE(on)}$	$V_{CE}=-5\text{V}, I_C=-10\text{mA}$			-0.82	V
Collector output capacitance	$C_{ob}$	$V_{CB}=-10\text{V}, I_E=0, f=1\text{MHz}$			4.5	pF
Transition frequency	$f_T$	$V_{CE}=-5\text{V}, I_C=-10\text{mA}, f=100\text{MHz}$	100			MHz
Noise figure	NF	$V_{CE}=-5\text{V}, I_c=-0.2\text{mA},$ $f=1\text{kHz}, R_g=2\text{K}\Omega, \Delta f=200\text{Hz}$			10	dB





# Package outline dimensions

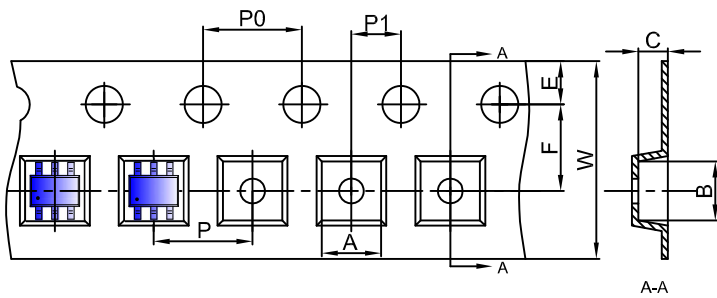
## SOT-363



Symbol	Dimension in Millimeters	
	Min	Max
A	0.900	1.100
A1	0.000	0.100
A2	0.900	1.000
b	0.150	0.350
c	0.080	0.150
D	2.000	2.200
E	1.150	1.350
E1	2.150	2.450
e	0.650 TYP	
e1	1.200	1.400
L	0.525 REF	
L1	0.260	0.460
$\theta$	0°	8°

# SOT-363 Tape and Reel

## SOT-363 Embossed Carrier Tape

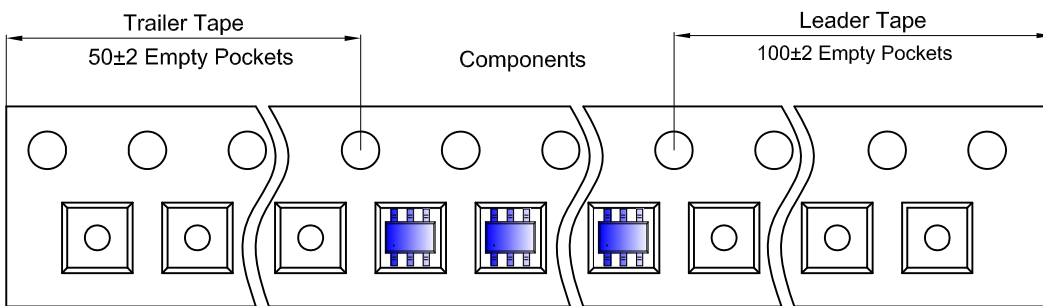


### Packaging Description:

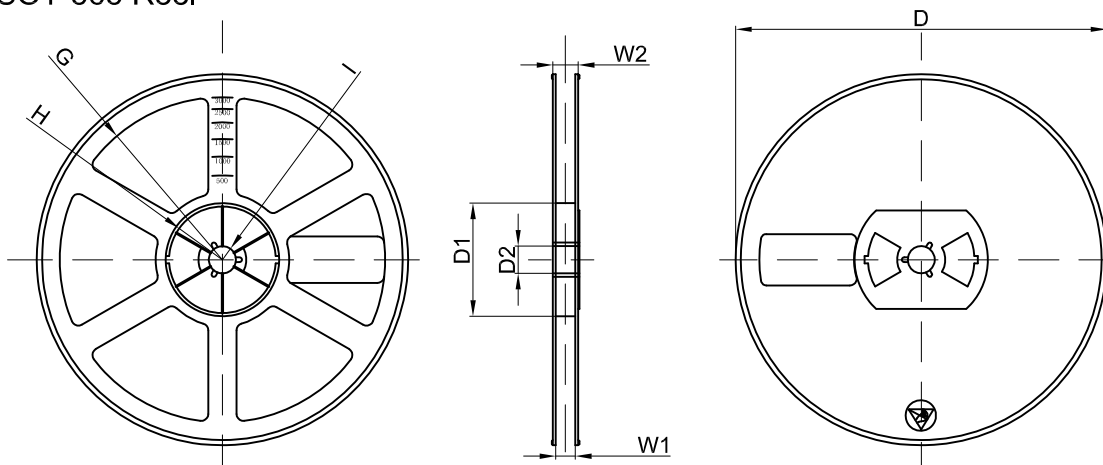
SOT-363 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-363	2.25	2.55	1.20	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

## SOT-363 Tape Leader and Trailer



## SOT-363 Reel



Dimensions are in millimeter								
Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	